



# RS3A THRU RS3M

## SURFACE MOUNT FAST RECOVERY RECTIFIER

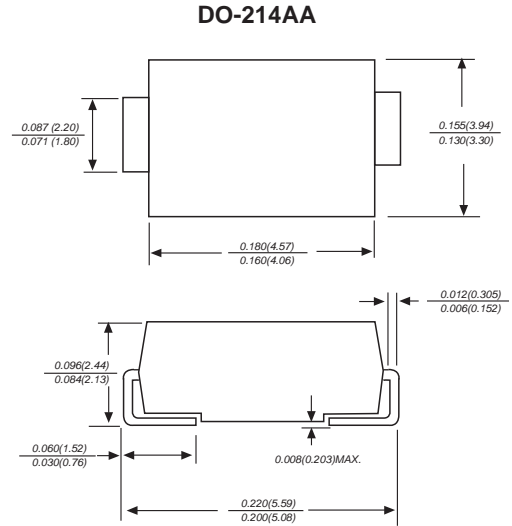
Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Amperes

### FEATURES

The plastic package carries Underwriters Laboratory  
Flammability Classification 94V-0  
For surface mounted applications  
Low reverse leakage  
Built-in strain relief, ideal for automated placement  
High forward surge current capability  
High temperature soldering guaranteed:  
250°C/10 seconds at terminals  
Glass passivated chip junction

### MECHANICAL DATA

**Case:** JEDEC DO-214AA molded plastic body over passivated chip  
**Terminals:** Solder plated, solderable per MIL-STD-750,  
Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.003 ounce, 0.093grams



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	100.0							Amps
Maximum instantaneous forward voltage at 3.0A	$V_F$	1.3							Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	5.0 200.0							$\mu\text{A}$
Maximum reverse recovery time (NOTE 1)	$t_{rr}$	150			250		500		ns
Typical junction capacitance (NOTE 2)	$C_J$	60.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	50.0							$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +150							$^\circ\text{C}$

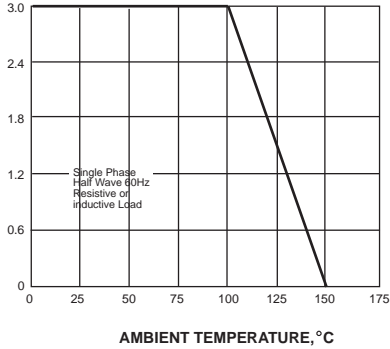
**Note:** 1. Reverse recovery condition  $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$   
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 3. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas



# RATINGS AND CHARACTERISTIC CURVES RS3A THRU RS3M

AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

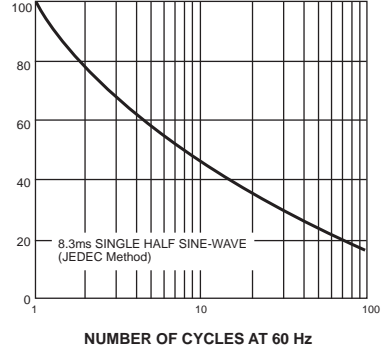


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

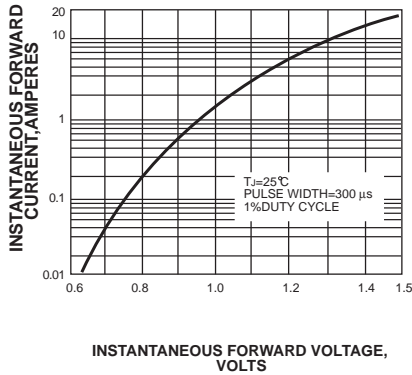


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

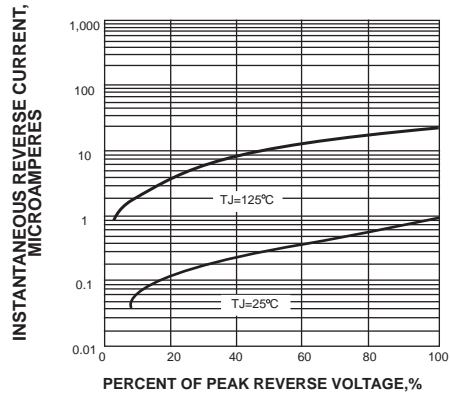


FIG. 5-TYPICAL JUNCTION CAPACITANCE

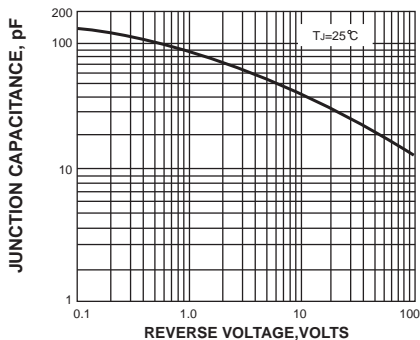
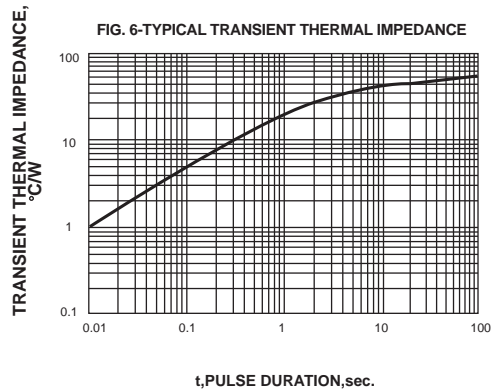


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



单击下面可查看定价，库存，交付和生命周期等信息

[>>ZG\(中鑫半导体\)](#)